

#### 30V N-CHANNEL ENHANCEMENT MODE MOSFET

#### **Product Summary**

BV <sub>DSS</sub>	Max R <sub>DS(ON)</sub>	I <sub>D</sub> Max T <sub>A</sub> = +25°C
201/	460mΩ @ V <sub>GS</sub> = 4.5V	0.9A
30V	560mΩ @ V <sub>GS</sub> = 2.5V	0.83A

# Features and Benefits

- Low V<sub>GS(TH),</sub> can be Driven Directly from a Battery
- Low R<sub>DS(ON)</sub>
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

## **Description and Applications**

This MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) yet maintain superior switching performance, which makes it ideal for high-efficiency power management applications.

- Load Switch
- Portable Applications
- Power Management Functions

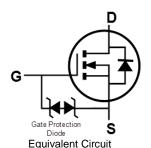
#### **Mechanical Data**

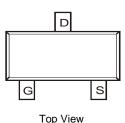
- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Annealed over Copper Leadframe.
   Solderable per MIL-STD-202, Method 208 ©3
- Terminals Connections: See Diagram Below
- Weight: 0.009 grams (Approximate)





Top View





Pin-Out

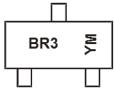
#### Ordering Information (Note 4)

Part Number	Marking	Reel size (inches)	Quantity per Reel
DMN3731U-7	BR3	7	3,000
DMN3731U-13	BR3	13	10,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

#### **Marking Information**



BR3 = Product Type Marking Code YM or YM = Date Code Marking Y or Y = Year (ex: G = 2019) M = Month (ex: 9 = September)

Date Code Key

Year	201	8	2019		2020	20	21	2022		2023	2	2024
Code	F		G		Н			J		K		L
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

DMN3731U Datasheet number: DS40980 Rev. 3 - 2



# Maximum Ratings (@T<sub>A</sub> = 25°C unless otherwise specified)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage	$V_{DSS}$	30	V	
Gate-Source Voltage	V <sub>GSS</sub>	±8	V	
Continuous Drain Current (Note 6) $V_{GS} = 4.5V$ Steady $T_A = +25^{\circ}C$ State $T_A = +70^{\circ}C$		I <sub>D</sub>	0.9 0.7	А
Maximum Continuous Body Diode Forward Curre	I <sub>S</sub>	0.55	Α	
Pulsed Drain Current (10µs Pulse, Duty Cycle =	1%)	I <sub>DM</sub>	3	A

### **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		$P_{D}$	0.4	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{\theta JA}$	303	°C/W
Total Power Dissipation (Note 6)		P <sub>D</sub>	0.58	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{\theta JA}$	215	°C/W
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C

## Electrical Characteristics (@T<sub>A</sub> = 25°C unless otherwise specified)

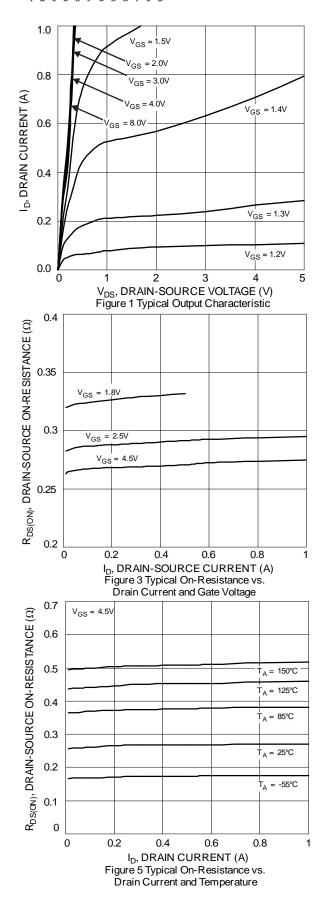
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Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	30	_	_	V	$V_{GS} = 0V, I_{D} = 10\mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	1	μΑ	$V_{DS} = 30V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS	_	_	3	μΑ	$V_{GS} = \pm 8V$ , $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	0.45	_	0.95	<b>V</b>	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$	
			271	460		$V_{GS} = 4.5V, I_D = 200mA$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	288	560	mΩ	$V_{GS} = 2.5V, I_D = 100mA$	
			324	730		$V_{GS} = 1.8V, I_D = 75mA$	
Diode Forward Voltage	V <sub>SD</sub>	_	0.7	1.2	V	$V_{GS} = 0V, I_{S} = 300mA$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C <sub>iss</sub>	1	73	_	рF	V 05V V 0V	
Output Capacitance	Coss	l	7.2	_	рF	$V_{DS} = 25V, V_{GS} = 0V,$ - f = 1.0MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>	_	5	_	pF	1 = 1.01/11 12	
Gate Resistance	$R_g$	l	902	_	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge	Qg	_	5.5	_	nC	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	
Gate-Source Charge	Qgs	_	0.8	_	nC	$V_{GS} = 4.5V, V_{DS} = 15V,$ $V_{DS} = 16V,$	
Gate-Drain Charge	$Q_{gd}$	_	1.4	_	nC	JID = IA	
Turn-On Delay Time	t <sub>D(ON)</sub>	_	2.5	_	ns		
Turn-On Rise Time	t <sub>R</sub>	_	3.1	_	ns	$V_{DS} = 10V, I_{D} = 1A$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	477	_	ns	$V_{GS} = 10V, R_g = 6\Omega$	
Turn-Off Fall Time	t <sub>F</sub>	_	123	_	ns		
Reverse Recovery Time	t <sub>RR</sub>	_	59	_	ns	1 44 4:/44 4004/	
Reverse Recovery Charge	Q <sub>RR</sub>	_	25	_	nC	I <sub>F</sub> = 1A, di/dt = 100A/μs	

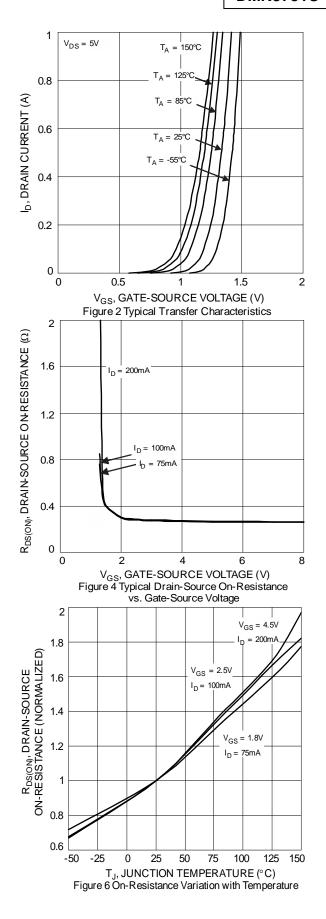
Notes:

- Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
   Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
   Short duration pulse test used to minimize self-heating effect.

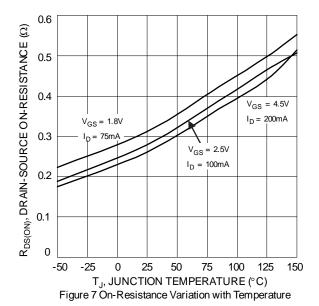
- 8. Guaranteed by design. Not subject to production testing.

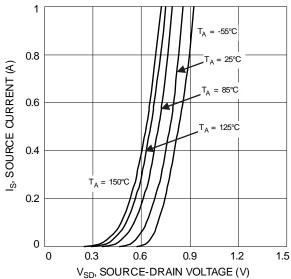


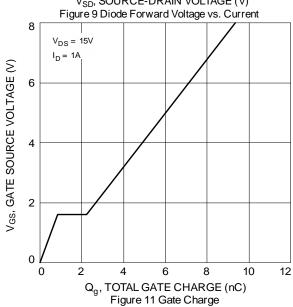


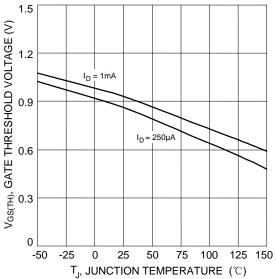




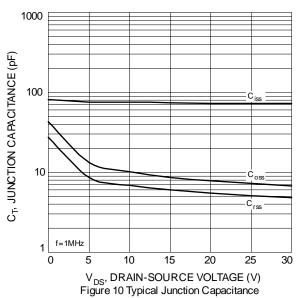








 $\rm T_{J},\, JUNCTION\,\, TEMPERATURE\,\,\,(^{\circ}\!C)$  Figure 8 Gate Threshold Variation vs. Junction Temperature



10 R<sub>DS(on Limited</sub> I<sub>D</sub>, DRAIN CURRENT (A) 0.1 0.01 T<sub>J(max)</sub> = 150°C

T<sub>C</sub> = 25°C

V<sub>GS</sub> = 4.5V

Single Pulse
DUT on 1\*MRP Board

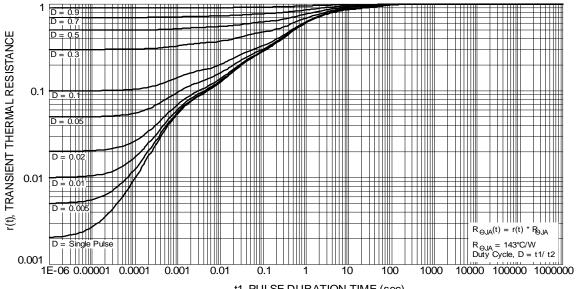
 ${
m V_{DS}}$  DRAIN-SOURCE VOLTAGE (V) Figure # SOA, Safe Operation Area

10

0.001

100



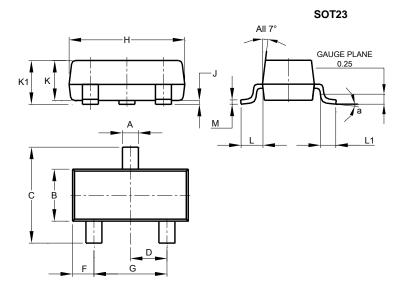


t1, PULSE DURATION TIME (sec) Figure 13 Transient Thermal Resistance



### **Package Outline Dimensions**

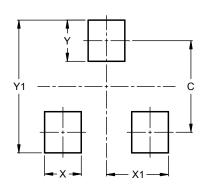
Please see http://www.diodes.com/package-outlines.html for the latest version.



	SOT23							
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
C	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
Н	2.80	3.00	2.90					
J	0.013	0.10	0.05					
K	0.890	1.00	0.975					
K1	0.903	1.10	1.025					
L	0.45	0.61	0.55					
L1	0.25	0.55	0.40					
M	0.085	0.150	0.110					
а	0°	8°						
All	All Dimensions in mm							

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



#### SOT23

Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Υ	0.9
Y1	2.9



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